

RF Low Noise FET CE3514M4

12GHz Low Noise FET in Dual Mold Plastic PKG

DESCRIPTION

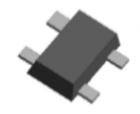
- Low Noise and High Gain
- Original Dual Mold Plastic package

FEATURES

 Low noise figure and high associated gain NF=0.42dB TYP., Ga=12.2dB TYP. @VDS=2V, ID=10mA, f=12GHz

PACKAGE

 Flat-lead 4-pin thin-type super minimold package



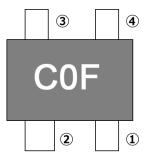
APPLICATIONS

- DBS LNB gain-stage, Mix-stage
- Low noise amplifier for microwave communication systems

ORDERING INFORMATION

Part Number	Order Number	Package	Marking	Description
CE3514M4	CE3514M4-C2	Flat-lead 4-pin thin-type super minimold package	COF	 Embossed tape 8 mm wide Pin 1(Source), Pin 2 (Drain) Face the perforation side of the Tape MOQ 15 kpcs/reel

PIN CONFIGURATION :



PIN No.	PIN Name
1	Source
2	Drain
3	Source
4	Gate

ABSOLUTE MAXIMUM RATINGS

(TA = +25°C, unless otherwise specified)

Parameter	Symbol	Rating	Unit
Drain to Source Voltage	V _{DS}	4.0	V
Gate to Source Voltage	V _{GS}	-3.0	V
Drain Current	Ι _D	I _{DSS}	mA
Gate Current	l _G	80	μA
Total Power Dissipation	P _{tot}	125	mW
Channel Temperature	T _{ch}	+150	°C
Storage Temperature	T _{stg}	-55 to +125	°C
Operation Temperature	T _{op}	-55 to +125 ^{Note}	°C

Note Refer to Total Power Dissipation vs. Ambient Temperature graph on page 4

RECOMMENDED OPERATING RANGE

 $(TA = +25^{\circ}C, unless otherwise specified)$

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Drain to Source Voltage	V _{DS}	+1	+2	+3	V
Drain Current	I _D	5	10	15	mA

ELECTRICAL CHARACTERISTICS

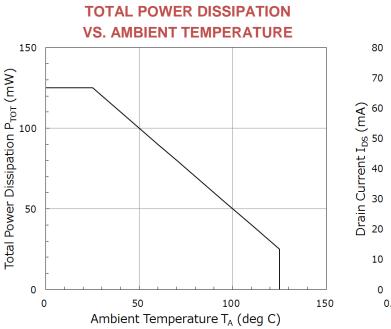
$(TA = +25^{\circ}C, unless otherwise specified)$

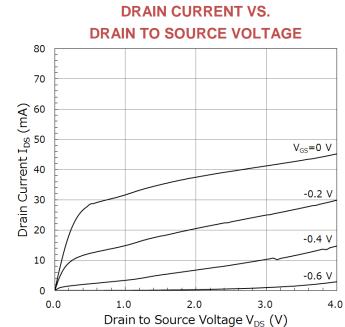
Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Gate to Source Leak Current	I _{GSO}	$V_{GS} = -3.0V$	-	0.4	10	μA
Saturated Drain Current	I _{DSS}	$V_{DS} = 2V, V_{GS} = 0V$	27	47.5	68	mA
Gate to Source Cut-off Voltage	$V_{GS(off)}$	$V_{DS} = 2V, I_D = 120\mu A$	-1.10	-0.75	-0.39	V
Transconductance	Gm	$V_{DS} = 2V, I_D = 10mA$	54	69	-	mS
Noise Figure	NF	$V_{DS} = 2V, I_{D} = 10mA,$	-	0.42	0.62	dB
Associated Gain	Ga	f = 12GHz	10.5	12.2	-	dB



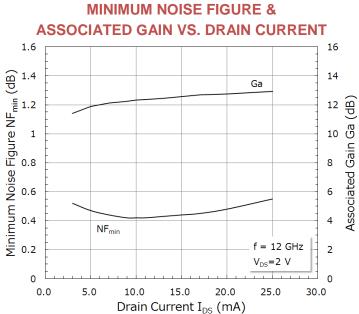
TYPICAL CHARACTERISTICS :

(TA=+25℃, unless otherwise specified)





DRAIN CURRENT VS. GATE TO SOURCE VOLTAGE





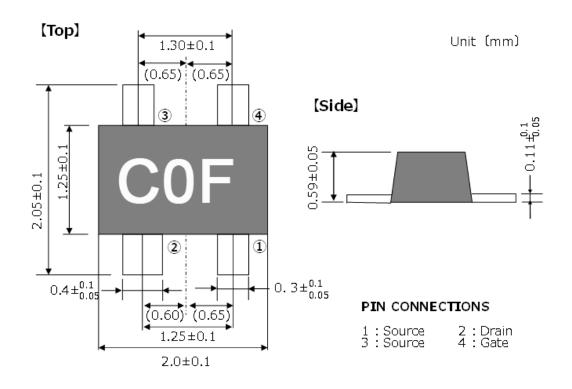
S-PARAMETERS

S-Parameters are available on the CEL web site.

RECOMMENDED SOLDERING CONDITIONS

Recommended Soldering Conditions are provided on the CEL web site.

PACKAGE DIMENSIONS





REVISION HISTORY

Version	Change to current version	Page(s)
CDS-0021-02 (Issue A) July 28, 2016	Initial datasheet	N/A



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[CAUTION]

Although this device is designed to be as robust as possible, ESD (Electrostatic Discharge) can damage this device. This device must be protected at all times from ESD. Static charges may easily produce potentials of several kilovolts on the human body or equipment, which can discharge without detection. Industry-standard ESD precautions should be used at all times.

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